

REVISIONS			
LTR	DESCRIPTION	DATE	APPROVED
A	Make clarification to paragraph 1.2.2 and update the boilerplate paragraphs. Add a footnote to Table I and paragraph 6.3. Make changes to the notes under figure 1. - ro	09-03-10	R. HEBER
B	Update document paragraphs to current requirements. - ro	19-04-17	C. SAFFLE



CURRENT DESIGN ACTIVITY CAGE CODE 16236  
HAS CHANGED NAMES TO:  
DLA LAND AND MARITIME  
COLUMBUS, OHIO 43218-3990

Prepared in accordance with ASME Y14.24

Vendor item drawing

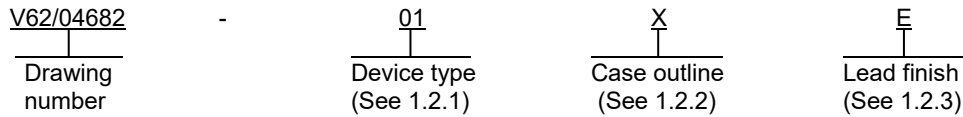
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PMIC N/A	PREPARED BY RICK OFFICER	DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990	
Original date of drawing YY-MM-DD  04-02-12	CHECKED BY TOM HESS	TITLE MICROCIRCUIT, LINEAR, DUAL/QUAD, RAIL TO RAIL, LOW POWER, OPERATIONAL AMPLIFIER, MONOLITHIC SILICON	
	APPROVED BY RAYMOND MONNIN		
	SIZE A	CODE IDENT. NO. 16236	DWG NO. <b>V62/04682</b>
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1. SCOPE

1.1 Scope. This drawing documents the general requirements of a high performance dual / quad rail to rail, low power, operational amplifier microcircuit, with an operating temperature range of -40°C to +125°C.

1.2 Vendor Item Drawing Administrative Control Number. The manufacturer's PIN is the item of identification. The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation:



1.2.1 Device type(s).

<u>Device type</u>	<u>Generic</u>	<u>Circuit function</u>
01	TLC2252	Dual, rail to rail, low power, operational amplifier
02	TLC2252A	Dual, rail to rail, low power, operational amplifier with enhanced VIO
03	TLC2254	Quad, rail to rail, low power, operational amplifier
04	TLC2254A	Quad, rail to rail, low power, operational amplifier with enhanced VIO

1.2.2 Case outline(s). The case outline(s) are as specified herein.

<u>Outline letter</u>	<u>Number of pins</u>	<u>JEDEC PUB 95</u>	<u>Package style</u>
X	8	MS-012-AA	Plastic surface mount
Y	14	MS-012-AB	Plastic surface mount

1.2.3 Lead finishes. The lead finishes are as specified below or other lead finishes as provided by the device manufacture:

<u>Finish designator</u>	<u>Material</u>
A	Hot solder dip
B	Tin-lead plate
C	Gold plate
D	Palladium
E	Gold flash palladium
F	Tin-lead alloy (BGA/CGA)
Z	Other

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1.3 Absolute maximum ratings. 1/

Supply voltage range (+VDD) .....	+8 V 2/
Supply voltage range (-VDD) .....	-8 V 2/
Differential input voltage (VID) .....	±16 V 3/
Input voltage range (VI) (any input) .....	±8 V 2/
Input current (II) (each input) .....	±5 mA
Output current (IO) .....	±50 mA
Total current into +VDD .....	±50 mA
Total current into -VDD .....	±50 mA
Duration of short-circuit current (at or below) 25°C .....	Unlimited 4/
Continuous total dissipation (PD) .....	See 1.5, Dissipation rating table
Operating free-air temperature range (TA) (Q suffix) .....	-40°C to +125°C
Storage temperature range (TSTG) .....	-65°C to +150°C
Lead temperature, 1.6 mm (1/16 inch) from case for 10 seconds .....	+260°C

1.4 Recommended operating conditions. 5/

Supply voltage (±VDD) .....	±2.2 V minimum to ±8 V maximum
Input voltage range (VI) .....	-VDD minimum to +VDD -1.5 V maximum
Common mode input voltage (VIC) .....	-VDD minimum to +VDD -1.5 V maximum
Operating free-air temperature range (TA) .....	-40°C to +125°C

1.5 Dissipation rating table.

Package	TA ≤ 25°C power rating	Derating factor above TA = 25°C	TA = 70°C power rating	TA = 85°C power rating	TA = 125°C power rating
X	724 mW	5.8 mW/°C	464 mW	377 mW	144 mW
Y	950 mW	7.6 mW/°C	608 mW	450 mW	190 mW

- 1/ Stresses beyond those listed under “absolute maximum rating” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2/ All voltage values, except differential voltages, are with respect to +VDD and -VDD.
- 3/ Differential voltages are at the +IN with respect to the -IN. Excessive current flows when input is brought below -VDD -0.3 V.
- 4/ The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.
- 5/ Use of this product beyond the manufacturers design rules or stated parameters is done at the user’s risk. The manufacturer and/or distributor maintain no responsibility or liability for product used beyond the stated limits.

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2. APPLICABLE DOCUMENTS

JEDEC Solid State Technology Association

JEDEC PUB 95 – Registered and Standard Outlines for Semiconductor Devices

(Copies of these documents are available online at <https://www.jedec.org>.)

3. REQUIREMENTS

3.1 Marking. Parts shall be permanently and legibly marked with the manufacturer's part number as shown in 6.3 herein and as follows:

- A. Manufacturer's name, CAGE code, or logo
- B. Pin 1 identifier
- C. ESDS identification (optional)

3.2 Unit container. The unit container shall be marked with the manufacturer's part number and with items A and C (if applicable) above.

3.3 Electrical characteristics. The maximum and recommended operating conditions and electrical performance characteristics are as specified in 1.3, 1.4, and table I herein.

3.4 Design, construction, and physical dimension. The design, construction, and physical dimensions are as specified herein.

3.5 Diagrams.

3.5.1 Case outlines. The case outlines shall be as shown in 1.2.2 and figure 1.

3.5.2 Terminal connections. The terminal connections shall be as shown in figure 2.

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TABLE I. Electrical performance characteristics. 1/

Test	Symbol	Conditions VDD = 5 V, unless otherwise specified	Temperature, 2/ TA	Device type	Limits		Unit
					Min	Max	
Input offset voltage	VIO	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C	01		1500	$\mu\text{V}$
				02		850	
			-40°C to +125°C	01		1750	
				02		1000	
Temperature coefficient of input offset voltage	$\alpha V_{IO}$	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C to +125°C	01,02	0.5 typical		$\mu\text{V} / ^\circ\text{C}$
Input offset voltage 3/ long term drift	DVIO	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C	01,02	0.003 typical		$\mu\text{V} / \text{mo}$
Input offset current	IIO	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C	01,02		60	pA
			-40°C to +125°C			1000	
Input bias current	IIB	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C	01,02		60	pA
			-40°C to +125°C			1000	
Common mode input voltage range	VICR	$ V_{IO}  \leq 5 \text{ mV}$ , $R_S = 50 \Omega$	25°C	01,02	0 to 4		V
			-40°C to +125°C		0 to 3.5		
High level output voltage	VOH	$I_{OH} = -20 \mu\text{A}$	25°C	01,02	4.98 typical		V
			25°C		4.9		
			-40°C to +125°C		4.8		
			25°C		4.8		
Low level output voltage	VOL	$V_{IC} = 2.5 \text{ V}$ , $I_{OL} = 50 \mu\text{A}$	25°C	01,02	0.01 typical		V
			25°C			0.15	
		-40°C to +125°C			0.15		
		$V_{IC} = 2.5 \text{ V}$ , $I_{OL} = 4 \text{ mA}$	25°C			1	
			-40°C to +125°C			1.2	

See footnotes at end of table.

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See footnotes at end of table.

Test	Symbol	Conditions VDD = 5 V, unless otherwise specified	Temperature, 2/ TA	Device type	Limits Min Max	Unit
Large signal differential voltage amplification	AVD	VIC = 2.5 V, VO = 1 V to 4 V, RL = 100 kΩ referenced to 2.5 V	25°C	01,02	100	V / mV
		VIC = 2.5 V, VO = 1 V to 4 V, RL = 1 MΩ referenced to 2.5 V	-40°C to +125°C		10	
Differential input resistance	r(d)		25°C	01,02	10 <sup>12</sup> typical	Ω
	r(c)		25°C		10 <sup>12</sup> typical	Ω
Common mode input capacitance	ci(c)	f = 10 kHz	25°C	01,02	8 typical	PF
Closed loop output impedance	zo	f = 25 kHz, AV = 10	25°C	01,02	200 typical	Ω
Common mode rejection ratio	CMRR	VIC = 0 V to 2.7 V, VO = 2.5 V, RS = 50 Ω	25°C	01,02	70	dB
			-40°C to +125°C		70	
Supply voltage rejection ratio (ΔVDD / ΔVIO)	KSVR	VDD = 4.4 V to 16 V, no load, VIC = VDD / 2	25°C	01,02	80	dB
			-40°C to +125°C		80	
Supply current	IDD	VO = 2.5 V, no load	25°C	01,02	125	μA
			-40°C to +125°C		150	
Slew rate at unity gain	SR	VO = 0.5 V to 3.5 V, RL = 100 kΩ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	01,02	0.07	V / μs
			-40°C to +125°C		0.05	
Equivalent input noise voltage	Vn	f = 10 Hz	25°C	01,02	36 typical	nV / √Hz
		f = 1 kHz			19 typical	
Peak to peak equivalent input noise voltage	VN(pp)	f = 0.1 Hz to 1 Hz	25°C	01,02	0.7 typical	μV
		f = 0.1 Hz to 10 Hz			1.1 typical	

TABLE 1. Electrical performance characteristics – continued. 1/

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TABLE 1. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions VDD = 5 V, unless otherwise specified	Temperature, 2/	Device type	Limits		Unit
					Min	Max	
Equivalent input noise current	In		25°C	01,02	0.6 typical		fA / $\sqrt{\text{Hz}}$
Total harmonic distortion plus noise	THD+N	AV = 1, VO = 0.5 V to 2.5 V, f = 10 kHz, RL = 50 k $\Omega$ referenced to 2.5 V	25°C	01,02	0.2 % typical		
		AV = 10, VO = 0.5 V to 2.5 V, f = 10 kHz, RL = 50 k $\Omega$ referenced to 2.5 V			1 % typical		
Gain bandwidth product	GBWP	f = 50 kHz, RL = 50 k $\Omega$ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	01,02	0.2 typical		MHZ
Maximum output swing bandwidth	BOM	VO(P) = 2 V, AV = 1, RL = 50 k $\Omega$ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	01,02	30 typical		KHZ
Phase margin at unity gain	$\phi_m$	RL = 50 k $\Omega$ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	01,02	63° typical		
Gain margin	Gm	RL = 50 k $\Omega$ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	01,02	15 typical		dB

1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.

2/ Full range is -40°C to +125°C for Q suffix.

3/ Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at TA = 150°C extrapolated to TA = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions $\pm V_{DD} = \pm 5\text{ V}$ , unless otherwise specified	Temperature, <sup>2/</sup> T <sub>A</sub>	Device type	Limits		Unit
					Min	Max	
Input offset voltage	V <sub>IO</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C	01		1500	μV
				02		850	
			-40°C to +125°C	01		1750	
				02		1000	
Temperature coefficient of input offset voltage	αV <sub>IO</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C to +125°C	01,02	0.5 typical		μV / °C
Input offset voltage <sup>3/</sup> long term drift	DV <sub>IO</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C	01,02	0.003 typical		μV / mo
Input offset current	I <sub>IO</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C	01,02		60	pA
			-40°C to +125°C			1000	
Input bias current	I <sub>IB</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C	01,02		60	pA
			-40°C to +125°C			1000	
Common mode input voltage range	V <sub>ICR</sub>	V <sub>IO</sub>   ≤ 5 mV, R <sub>S</sub> = 50 Ω	25°C	01,02	-5 to 4		V
			-40°C to +125°C		-5 to 3.5		
Maximum positive peak output voltage	+V <sub>OM</sub>	I <sub>O</sub> = -20 μA	25°C	01,02	4.98 typical		V
		I <sub>O</sub> = -100 μA	25°C		4.9		
			-40°C to +125°C		4.7		
		I <sub>O</sub> = -200 μA	25°C		4.8		
Maximum negative peak output voltage	-V <sub>OM</sub>	V <sub>IC</sub> = 0 V, I <sub>O</sub> = 50 μA	25°C	01,02	-4.99 typical		V
		V <sub>IC</sub> = 0 V, I <sub>O</sub> = 500 μA	25°C		-4.85		
			-40°C to +125°C		-4.85		
		V <sub>IC</sub> = 0 V, I <sub>O</sub> = 4 mA	25°C		-4		
			-40°C to +125°C		-3.8		

See footnotes at end of table.

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See footnotes at end of table.

Test	Symbol	Conditions $\pm V_{DD} = \pm 5V$ , unless otherwise specified	Temperature, $T_A$ Device type	Limits		Unit
Large signal differential voltage amplification	AVD	$V_O = \pm 4V$ , $R_L = 100k\Omega$	25°C	01,02	3000 typical	V/mV
					10	
					40	
Differential input resistance	r <sub>i</sub> (d)		25°C	01,02	$10^{12}$ typical	$\Omega$
Common mode input resistance	r <sub>i</sub> (c)		25°C	01,02	$10^{12}$ typical	$\Omega$
Common mode input capacitance	c <sub>i</sub> (c)	$f = 10\text{ KHz}$ , X package	25°C	01,02	8 typical	pF
Closed loop output impedance	z <sub>o</sub>	$f = 25\text{ KHz}$ , $A_V = 10$	25°C	01,02	190 typical	$\Omega$
Common mode rejection ratio	CMRR	$V_{IC} = -5V$ to $2.7V$ , $V_O = 0V$ , $R_S = 50\Omega$	25°C	01,02	75	dB
			-40°C to +125°C		75	
Supply voltage rejection ratio ( $\Delta V_{DD} / \Delta V_{IO}$ )	KSVR	$V_{DD} = \pm 2.2V$ to $\pm 8V$ , no load, $V_{IC} = 0$	25°C	01,02	80	dB
			-40°C to +125°C		80	
Supply current	IDD	$V_O = 2.5V$ , no load	25°C	01,02	125	$\mu A$
			-40°C to +125°C		150	
Slew rate at unity gain	SR	$V_O = \pm 2V$ , $R_L = 100k\Omega$ , $C_L = 100pF$	25°C	01,02	0.07	V / $\mu s$
			-40°C to +125°C		0.05	
Equivalent input noise voltage	v <sub>n</sub>	$f = 10\text{ Hz}$	25°C	01,02	38 typical	nV / $\sqrt{Hz}$
					19 typical	
Peak to peak equivalent input noise voltage	VN(pp)	$f = 0.1\text{ Hz}$ to $1\text{ Hz}$	25°C	01,02	0.8 typical	$\mu V$
					1.1 typical	

TABLE I. Electrical performance characteristics – continued. 1/

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1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.

2/ Full range is -40°C to +125°C for Q suffix.

3/ Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at TA = 150°C extrapolated to TA = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

Test	Symbol	Conditions ±VDD = ±5 V, TA Temperature, 2/	Device type	Limits		Unit
				Min	Max	
Equivalent input noise current	In	25°C	01,02	0.6 typical		fA / √Hz
Total harmonic distortion plus noise	THD+N	25°C	01,02	0.2 % typical		
				1 % typical		
Gain bandwidth product	GBWP	f = 10 kHz, RL = 50 kΩ, CL = 100 pF	25°C	01,02	0.21 typical	
Maximum output swing bandwidth	BOM	VO(PP) = 4.6 V, AV = 1, RL = 50 kΩ, CL = 100 pF	25°C	01,02	14 typical	
Phase margin at unity gain	φm	RL = 50 kΩ, CL = 100 pF	25°C	01,02	63° typical	
Gain margin	Gm	RL = 50 kΩ, CL = 100 pF	25°C	01,02	15 typical	

TABLE 1. Electrical performance characteristics – continued. 1/

TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions VDD = 5 V, unless otherwise specified	Temperature, 2/ TA	Device type	Limits		Unit
					Min	Max	
Input offset voltage	VIO	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C	03		1500	$\mu\text{V}$
				04		850	
			-40°C to +125°C	03		1750	
				04		1000	
Temperature coefficient of input offset voltage	$\alpha V_{IO}$	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C to +125°C	03,04	0.5 typical		$\mu\text{V} / ^\circ\text{C}$
Input offset voltage 3/ long term drift	DVIO	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C	03,04	0.003 typical		$\mu\text{V} / \text{mo}$
Input offset current	IIO	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C	03,04		60	pA
			+125°C			1000	
Input bias current	IIB	$\pm V_{DD} = \pm 2.5 \text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50 \Omega$	25°C	03,04		60	pA
			+125°C			1000	
Common mode input voltage range	VICR	$ V_{IO}  \leq 5 \text{ mV}$ , $R_S = 50 \Omega$	25°C	03,04	0 to 4		V
			-40°C to +125°C		0 to 3.5		
High level output voltage	VOH	$I_{OH} = -20 \mu\text{A}$	25°C	03,04	4.98 typical		V
			25°C		4.9		
			-40°C to +125°C		4.8		
			25°C		4.8		
Low level output voltage	VOL	$V_{IC} = 2.5 \text{ V}$ , $I_{OL} = 50 \mu\text{A}$	25°C	03,04	0.01 typical		mV
			25°C			0.15	
		-40°C to +125°C			0.15		
		$V_{IC} = 2.5 \text{ V}$ , $I_{OL} = 4 \text{ mA}$	25°C			1	
			-40°C to +125°C			1.2	

See footnotes at end of table.

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See footnotes at end of table.

Test	Symbol	Conditions VDD = 5 V, unless otherwise specified	Temperature, 2/ TA	Device type	Limits	Unit
Large signal differential voltage amplification	AVD	VIC = 2.5 V, VO = 1 V to 4 V, RL = 100 kΩ referenced to 2.5 V	25°C	03,04	100	V/mV
		VIC = 2.5 V, VO = 1 V to 4 V, RL = 1 MΩ referenced to 2.5 V	25°C		10	
Differential input resistance	ri(d)		25°C	03,04	10 <sup>12</sup> typical	Ω
Common mode input resistance	ri(c)		25°C	03,04	10 <sup>12</sup> typical	Ω
Common mode input capacitance	ci(c)	f = 10 KHz, Y package	25°C	03,04	8 typical	pF
Closed loop output impedance	zo	f = 25 KHz, AV = 10	25°C	03,04	200 typical	Ω
Common mode rejection ratio	CMRR	VIC = 0 V to 2.7 V, VO = 2.5 V, RS = 50 Ω	25°C	03,04	70	dB
			-40°C to +125°C		70	
Supply voltage rejection ratio (ΔVDD / ΔVIO)	KSVR	VDD = 4.4 V to 16 V, no load, VIC = VDD / 2	25°C	03,04	80	dB
			-40°C to +125°C		80	
Supply current (four amplifiers)	IDD	VO = 2.5 V, no load	25°C	03,04	250	μA
			-40°C to +125°C		300	
Slew rate at unity gain	SR	VO = 0.5 V to 3.5 V, RL = 100 kΩ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	03,04	0.07	V / μs
			-40°C to +125°C		0.05	
Equivalent input noise voltage	Vn	f = 10 Hz	25°C	03,04	36 typical	nV / √Hz
		f = 1 KHz	25°C		19 typical	
Peak to peak equivalent input noise voltage	VN(pp)	f = 0.1 Hz to 1 Hz	25°C	03,04	0.7 typical	μV
		f = 0.1 Hz to 10 Hz	25°C		1.1 typical	

TABLE 1. Electrical performance characteristics – continued. 1/

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DWG NO. V62/04682				

TABLE 1. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions VDD = 5 V, unless otherwise specified	Temperature, 2/	Device type	Limits		Unit
					Min	Max	
Equivalent input noise current	I <sub>n</sub>		25°C	03,04	0.6 typical		fA / √Hz
Total harmonic distortion plus noise	THD+N	Av = 1, VO = 0.5 V to 2.5 V, f = 20 kHz, RL = 50 kΩ referenced to 2.5 V	25°C	03,04	0.2 % typical		
		Av = 10, VO = 0.5 V to 2.5 V, f = 20 kHz, RL = 50 kΩ referenced to 2.5 V			1 % typical		
Gain bandwidth product	GBWP	f = 50 kHz, RL = 50 kΩ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	03,04	0.2 typical		MHZ
Maximum output swing bandwidth	BOM	VO(P) = 2 V, AV = 1, RL = 50 kΩ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	03,04	30 typical		KHZ
Phase margin at unity gain	φ <sub>m</sub>	RL = 50 kΩ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	03,04	63° typical		
Gain margin	G <sub>m</sub>	RL = 50 kΩ referenced to 2.5 V, CL = 100 pF referenced to 2.5 V	25°C	03,04	15 typical		dB

1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.

2/ Full range is -40°C to +125°C for Q suffix.

3/ Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at TA = 150°C extrapolated to TA = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

TABLE I. Electrical performance characteristics – continued. 1/

Test	Symbol	Conditions $\pm V_{DD} = \pm 5\text{ V}$ , unless otherwise specified	Temperature, <sup>2/</sup> T <sub>A</sub>	Device type	Limits		Unit
					Min	Max	
Input offset voltage	V <sub>IO</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C	03		1500	μV
				04		850	
			-40°C to +125°C	03		1750	
				04		1000	
Temperature coefficient of input offset voltage	αV <sub>IO</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C to +125°C	03,04	0.5 typical		μV / °C
Input offset voltage <sup>3/</sup> long term drift	DV <sub>IO</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C	03,04	0.003 typical		μV / mo
Input offset current	I <sub>IO</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C	03,04		60	pA
			+125°C			1000	
Input bias current	I <sub>IB</sub>	V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω	25°C	03,04		60	pA
			+125°C			1000	
Common mode input voltage range	V <sub>ICR</sub>	V <sub>IO</sub>   ≤ 5 mV, R <sub>S</sub> = 50 Ω	25°C	03,04	-5 to 4		V
			-40°C to +125°C		-5 to 3.5		
Maximum positive peak output voltage	+V <sub>OM</sub>	I <sub>O</sub> = -20 μA	25°C	03,04	4.98 typical		V
		I <sub>O</sub> = -100 μA	25°C		4.9		
			-40°C to +125°C		4.7		
		I <sub>O</sub> = -200 μA	25°C		4.8		
Maximum negative peak output voltage	-V <sub>OM</sub>	V <sub>IC</sub> = 0 V, I <sub>O</sub> = 50 μA	25°C	03,04	-4.99 typical		V
		V <sub>IC</sub> = 0 V, I <sub>O</sub> = 500 μA	25°C		-4.85		
			-40°C to +125°C		-4.85		
		V <sub>IC</sub> = 0 V, I <sub>O</sub> = 4 mA	25°C		-4		
			-40°C to +125°C		-3.8		

See footnotes at end of table.

<b>DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO</b>	<b>SIZE A</b>	<b>CODE IDENT NO. 16236</b>	<b>DWG NO. V62/04682</b>
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DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO	SIZE A	CODE IDENT NO. 16236	DWG NO. V62/04682
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See footnotes at end of table.

Test	Symbol	Conditions $\pm V_{DD} = \pm 5V$ , unless otherwise specified	Temperature, $T_A$ Device type	Limits		Unit
Large signal differential voltage amplification	AVD	$V_O = \pm 4V$ , $R_L = 100k\Omega$	25°C	03,04	3000 typical	V / mV
					10	
					40	
Differential input resistance	r <sub>i</sub> (d)		25°C	03,04	$10^{12}$ typical	$\Omega$
Common mode input resistance	r <sub>i</sub> (c)		25°C	03,04	$10^{12}$ typical	$\Omega$
Common mode input capacitance	c <sub>i</sub> (c)	$f = 10\text{ KHz}$ , Y package	25°C	03,04	8 typical	pF
Closed loop output impedance	z <sub>o</sub>	$f = 25\text{ KHz}$ , $A_V = 10$	25°C	03,04	190 typical	$\Omega$
Common mode rejection ratio	CMRR	$V_{IC} = -5V$ to $2.7V$ , $V_O = 0V$ , $R_S = 50\Omega$	25°C	03,04	75	dB
			-40°C to +125°C		75	
Supply voltage rejection ratio ( $\Delta V_{DD} / \Delta V_{IO}$ )	KSVR	$\pm V_{DD} = \pm 2.2V$ to $\pm 8V$ , no load, $V_{IC} = V_{DD} / 2$	25°C	03,04	80	dB
			-40°C to +125°C		80	
Supply current (four amplifiers)	IDD	$V_O = 0V$ , no load	25°C	03,04	250	$\mu A$
			-40°C to +125°C		300	
Slew rate at unity gain	SR	$V_O = \pm 2V$ , $R_L = 100k\Omega$ , $C_L = 100pF$	25°C	03,04	0.07	V / $\mu s$
			-40°C to +125°C		0.05	
Equivalent input noise voltage	v <sub>n</sub>	$f = 10\text{ Hz}$	25°C	03,04	38 typical	nV / $\sqrt{Hz}$
					19 typical	
Peak to peak equivalent input noise voltage	V <sub>N</sub> (PP)	$f = 0.1\text{ Hz}$ to $1\text{ Hz}$	25°C	03,04	0.8 typical	$\mu V$
					1.1 typical	

TABLE 1. Electrical performance characteristics – continued. 1/

DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO	SIZE A	CODE IDENT NO. 16236	DWG NO. V62/04682
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1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.

2/ Full range is -40°C to +125°C for Q suffix.

3/ Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at TA = 150°C extrapolated to TA = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

Test	Symbol	Conditions ±VDD = ±5 V, TA Temperature, 2/	Device type	Limits		Unit
				Min	Max	
Equivalent input noise current	In	25°C	03,04	0.6 typical		fA / $\sqrt{\text{Hz}}$
Total harmonic distortion plus noise	THD+N	25°C	03,04	0.2 % typical		
				1 % typical		
Gain bandwidth product	GBWP	25°C	03,04	0.21 typical		MHZ
Maximum output swing bandwidth	BOM	25°C	03,04	14 typical		KHZ
Phase margin at unity gain	$\phi_m$	25°C	03,04	63° typical		
Gain margin	Gm	25°C	03,04	15 typical		dB

TABLE 1. Electrical performance characteristics – continued. 1/



Case X

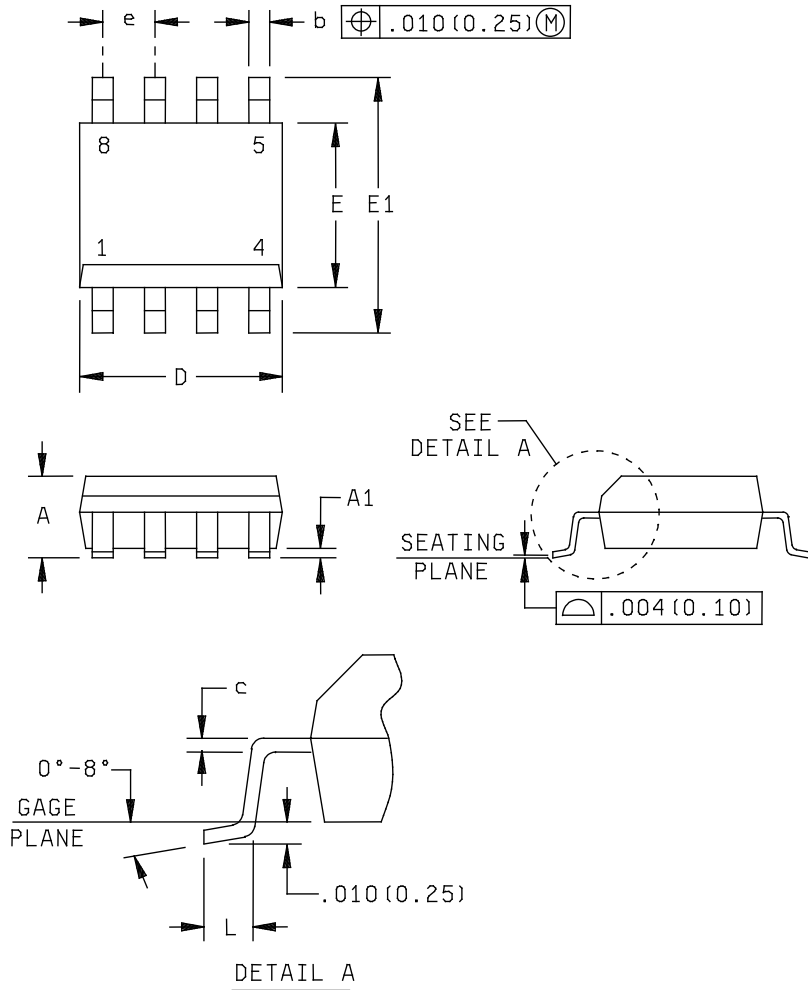


FIGURE 1. Case outlines.

<p><b>DEFENSE SUPPLY CENTER, COLUMBUS</b>  <b>COLUMBUS, OHIO</b></p>	<p>SIZE  <b>A</b></p>	<p>CODE IDENT NO.  <b>16236</b></p>	<p>DWG NO.  <b>V62/04682</b></p>
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Case X - Continued

Symbol	Dimensions			
	Inches		Millimeters	
	Min	Max	Min	Max
A	---	.069	---	1.75
A1	.004	.010	0.10	0.25
b	.012	.020	0.31	0.51
c	.005	.010	0.13	0.25
D	.189	.197	4.80	5.00
E	.150	.157	3.81	4.00
E1	.228	.244	5.80	6.20
e	.050 BSC		1.27 BSC	
L	.016	.050	0.40	1.27

NOTES:

1. Controlling dimensions are inch, millimeter dimensions are given for reference only.
2. For dimension D, body length does not include mold flash, protrusion, or gate burrs. Mold flash, protrusion, or gate burrs shall not exceed 0.006 inch (0.15 mm) per end.
3. For dimension E, body width does not include interlead flash. Interlead flash shall not exceed 0.017 inch (0.43 mm) per side.
4. Fall within JEDEC MS-012 variation AA.

FIGURE 1. Case outlines - Continued.

<b>DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO</b>	<b>SIZE A</b>	<b>CODE IDENT NO. 16236</b>	<b>DWG NO. V62/04682</b>
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Case Y

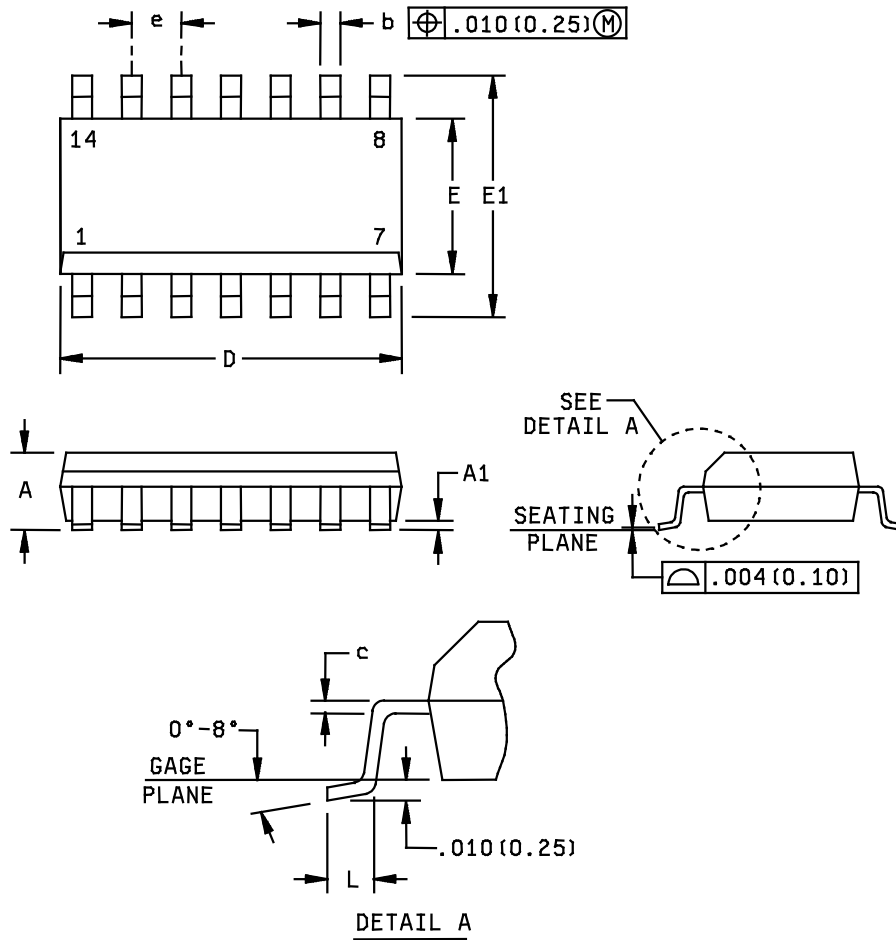


FIGURE 1. Case outlines – Continued.

<p><b>DEFENSE SUPPLY CENTER, COLUMBUS</b>  <b>COLUMBUS, OHIO</b></p>	<p>SIZE  <b>A</b></p>	<p>CODE IDENT NO.  <b>16236</b></p>	<p>DWG NO.  <b>V62/04682</b></p>
		<p>REV    B</p>	<p>PAGE    19</p>

Case Y - Continued

Symbol	Dimensions			
	Inches		Millimeters	
	Min	Max	Min	Max
A	---	.069	---	1.75
A1	.004	.010	0.10	0.25
b	.012	.020	0.31	0.51
c	.005	.010	0.13	0.25
D	.337	.344	8.55	8.75
E	.150	.157	3.80	4.00
E1	.228	.244	5.80	6.20
e	.050 BSC		1.27 BSC	
L	.016	.050	0.40	1.27

NOTES:

1. Controlling dimensions are inch, millimeter dimensions are given for reference only.
2. For dimension D, body length does not include mold flash, protrusion, or gate burrs. Mold flash, protrusion, or gate burrs shall not exceed 0.006 inch (0.15 mm) per end.
3. For dimension E, body width does not include interlead flash. Interlead flash shall not exceed 0.017 inch (0.43 mm) per side.
4. Fall within JEDEC MS-012 variation AB

FIGURE 1. Case outlines - Continued.

<b>DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO</b>	<b>SIZE A</b>	<b>CODE IDENT NO. 16236</b>	<b>DWG NO. V62/04682</b>
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Device types	01 and 02	03 and 04
Case outlines	X	Y
Terminal number	Terminal symbol	
1	OUT1	OUT1
2	-IN1	-IN1
3	+IN1	+IN1
4	-VDD / GND	+VDD
5	+IN2	+IN2
6	-IN2	-IN2
7	OUT2	OUT2
8	+VDD	OUT3
9	---	-IN3
10	---	+IN3
11	---	-VDD / GND
12	---	+IN4
13	---	-IN4
14	---	OUT4

FIGURE 2. Terminal connections.

<b>DEFENSE SUPPLY CENTER, COLUMBUS COLUMBUS, OHIO</b>	<b>SIZE A</b>	<b>CODE IDENT NO. 16236</b>	<b>DWG NO. V62/04682</b>
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4. VERIFICATION

4.1 Product assurance requirements. The manufacturer is responsible for performing all inspection and test requirements as indicated in their internal documentation. Such procedures should include proper handling of electrostatic sensitive devices, classification, packaging, and labeling of moisture sensitive devices, as applicable.

5. PREPARATION FOR DELIVERY

5.1 Packaging. Preservation, packaging, labeling, and marking shall be in accordance with the manufacturer's standard commercial practices for electrostatic discharge sensitive devices.

6. NOTES

6.1 ESDS. Devices are electrostatic discharge sensitive and are classified as ESDS class 1 minimum.

6.2 Configuration control. The data contained herein is based on the salient characteristics of the device manufacturer's data book. The device manufacturer reserves the right to make changes without notice. This drawing will be modified as changes are provided.

6.3 Suggested source(s) of supply. Identification of the suggested source(s) of supply herein is not to be construed as a guarantee of present or continued availability as a source of supply for the item. DLA Land and Maritime maintains an online database of all current sources of supply at <https://landandmaritimeapps.dla.mil/Programs/Smcr/>.

Vendor item drawing administrative control number <u>1/</u>	V <sub>IO</sub> max at 25°C	Device manufacturer CAGE code	Package <u>2/</u>		Vendor part number	Top side marking
V62/04682-01XE	1550 μV	01295	SOIC (D)	Tape and reel	TLC2252QDREP	2252EP
V62/04682-02XE	850 μV	01295	SOIC (D)	Tape and reel	TLC2252AQDREP	2252AE
V62/04682-03YE	1550 μV	<u>3/</u>	SOIC (D)	Tape and reel	TLC2254QDREP	TLC2254EP
V62/04682-04YE	850 μV	01295	SOIC (D)	Tape and reel	TLC2254AQDREP	TLC2254AEP

1/ The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation.

2/ Package drawings, standard packaging quantities, thermal data, symbolization, and printed circuit board (PCB) design guidelines are available from the manufacturer.

3/ No longer available from an approved source of supply.

CAGE code

01295

Source of supply

Texas Instruments, Inc.  
Semiconductor Group  
8505 Forest Lane  
P.O. Box 660199  
Dallas, TX 75243

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		<b>REV B</b>	<b>PAGE 22</b>